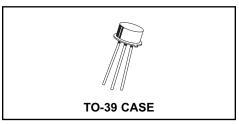
2N5333

PNP SILICON POWER TRANSISTOR





DESCRIPTION:

The CENTRAL SEMICONDUCTOR 2N5333 is a PNP Silicon Power Transistor manufactured by the epitaxial planar process, mounted in a hermetically sealed metal case, designed for amplifier and switching applications.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: (T _C =25°C)	SYMBOL		UNITS
Collector-Base Voltage	V_{CBO}	100	V
Collector-Emitter Voltage	V_{CEO}	80	V
Emitter-Base Voltage	V_{EBO}	6.0	V
Continuous Collector Current	I _C	2.0	Α
Peak Collector Current (t _p ≤ 0.3ms)	^I CM	5.0	Α
Continuous Base Current	Ι _Β	1.0	Α
Power Dissipation (T _A =25°C)	P_{D}	1.0	W
Operating and Storage Junction Temperature	T _J , T _{stg}	-65 to +200	°C
Thermal Resistance	ΘιΔ	175	°C/W

ELECTRICAL CHARACTERISTICS: (T_A=25°C unless otherwise noted)

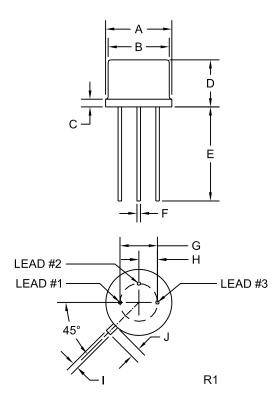
SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNITS
ICES	V _{CE} =90V			10	μA
ICES	V _{CE} =50V (T _C =150°C)			500	μΑ
ICEO	V _{CE} =40V			50	μA
I _{EBO}	V _{EB} =4.0V			1.0	μA
I _{EBO}	V _{EB} =6.0V			100	μA
BVCEO	I _C =30mA	80			V
V _{CE(SAT)}	I _C =1.0A, I _B =100mA			0.45	V
V _{CE} (SAT)	I _C =2.0A, I _B =400mA			1.0	V
V _{BE(ON)}	V_{CE} =4.0V, I_{C} =2.0A			1.5	V
h _{FE}	V_{CE} =4.0V, I_{C} =1.0A	30		120	
h _{FE}	V_{CE} =4.0V, I_{C} =2.0A	10			
h _{fe}	V_{CE} =10V, I_{C} =1.0A, f =1KHz	30			
f_T	V_{CE} =10V, I_{C} =1.0A	30			MHz
^t on	$\int I_C$ =1.0A, I_{B1} = I_{B2} =100mA		150		ns
^t off	$ \left\{ \begin{array}{l} I_{\text{C}} = 1.0 \text{A, } I_{\text{B1}} = I_{\text{B2}} = 100 \text{mA} \\ V_{\text{BE}(\text{OFF})} = 3.7 \text{V, } R_{\text{L}} = 20 \Omega \end{array} \right\} $		450		ns



2N5333

NPN SILICON POWER TRANSISTOR

TO-39 CASE - MECHANICAL OUTLINE



DIMENSIONS							
	INCHES		MILLIMETERS				
SYMBOL	MIN	MAX	MIN	MAX			
A (DIA)	0.335	0.370	8.51	9.40			
B (DIA)	0.315	0.335	8.00	8.51			
С	-	0.040	-	1.02			
D	0.240	0.260	6.10	6.60			
Е	0.500	-	12.70	-			
F (DIA)	0.016	0.021	0.41	0.53			
G (DIA)	0.200		5.08				
Н	0.100		2.54				
	0.028	0.034	0.71	0.86			
J	0.029	0.045	0.74	1.14			

TO-39 (REV: R1)

LEAD CODE:

- 1) EMITTER
- 2) BASE
- 3) COLLECTOR (case)

MARKING: FULL PART NUMBER

R0 (25-September 2008)

OUTSTANDING SUPPORT AND SUPERIOR SERVICES



PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- · Inventory bonding
- · Consolidated shipping options

- · Custom bar coding for shipments
- · Custom product packing

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free guick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- · Custom electrical curves
- · Environmental regulation compliance
- · Customer specific screening
- · Up-screening capabilities

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits
- Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- 2. If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

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